

Heisener.com

MT29F4T08EYCBBG9-37ES:B TR

MT29F4T08EYCBBG9-37ES:B TR Information

Part Number MT29F4T08EYCBBG9-37ES:B TR

Manufacturer Micron Technology Inc.

Category Integrated Circuits (ICs)

Memory

Description IC FLASH 4TBIT 267MHZ LBGA

Package -

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MT29F4T08EYCBBG9-37ES:B TR Specifications

	Report errors?
Supplier Device Package	-
Package / Case	-
Mounting Type	-
Operating Temperature	$0^{\circ}\text{C} \sim 70^{\circ}\text{C} \text{ (TA)}$
Voltage - Supply	2.7 V ~ 3.6 V
Access Time	-
Write Cycle Time - Word, Page	-
Clock Frequency	267MHz
Memory Interface	Parallel
Memory Size	4Tb (512G x 8)
Technology	FLASH - NAND
Memory Format	FLASH
Memory Type	Non-Volatile
Series	-
Package	-
	Memory
Category	Integrated Circuits (ICs)
Manufacturer	Micron Technology Inc.
Manufacturer Part Number	MT29F4T08EYCBBG9-37ES:B TR

MT29F4T08EYCBBG9-37ES:B TR Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MT29F4T08EYCBBG9-37ES:B TR Payment Methods



















MT29F4T08EYCBBG9-37ES:B TR Shipping Methods













If you have any question about MT29F4T08EYCBBG9-37ES:B TR, please do not hesitate to contact us!

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